TRANSISTOR

2N710

Germanium p-n-p type used in high-speed logic-circuit applications in data-processing equipment. JEDEC No. TO-18 package; outline 12, Outlines Section. This type is identical with type 2N705 except for the following items:

MAXIMUM RATINGS

Emitter-to-Base Voltage (with collector open) .... −2 max   volts

CHARACTERISTICS

Base-to-Emitter Voltage (with collector ma = −10 and base ma = −0.4) .... −0.5 max   volt
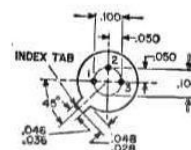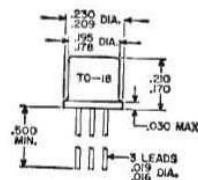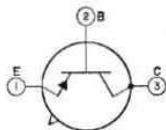
Collector-to-Emitter Saturation Voltage (with collector ma = −10 and base ma = −0.4) .... −0.5 max   volt

In Common-Emitter Circuit

Forward Current-Transfer Ratio (with collector-to-emitter volts = −0.5 and collector ma = −10) .... 25 min

− 12 −

http://alltransistors.com